FAIRCHILD SEMICONDUCTOR®

March 2008

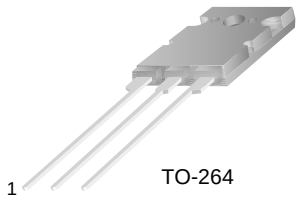
2SC5200/FJL4315
NPN Epitaxial Silicon Transistor

Applications

- High-Fidelity Audio Output Amplifier
- General Purpose Power Amplifier

Features

- High Current Capability: I_C = 15A.
- High Power Dissipation : 150watts.
- High Frequency : 30MHz.
- High Voltage : V_{CEO}=230V
- Wide S.O.A for reliable operation.
- Excellent Gain Linearity for low THD.
- Complement to 2SA1943/FJL4215.
- Thermal and electrical Spice models are available.
- Same transistor is also available in:
  -- TO3P package, 2SC5242/FJA4313 : 130 watts
  -- TO220 package, FJP5200 : 80 watts
  -- TO220F package, FJPF5200 : 50 watts



TO-264

1.Base 2.Collector 3.Emitter

Absolute Maximum Ratings* T_a = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
BV_{CBO}	Collector-Base Voltage	230	V
BV_{CEO}	Collector-Emitter Voltage	230	V
BV_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current(DC)	15	A
I_B	Base Current	1.5	A
P_D	Total Device Dissipation(T_C=25°C) Derate above 25°C	150 1.04	W W/°C
T_J, T_{STG}	Junction and Storage Temperature	- 50 ~ +150	°C

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics* T_a=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
$R_{\theta JC}$	Thermal Resistance, Junction to Case	0.83	°C/W

* Device mounted on minimum pad size

h_{FE} Classification

Classification	R	O
h_{FE1}	55 ~ 110	80 ~ 160

Electrical Characteristics* T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	I_C=5mA, I_E=0	230			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	I_C=10mA, R_{BE}=∞	230			V
BV_{EBO}	Emitter-Base Breakdown Voltage	I_E=5mA, I_C=0	5			V
I_{CBO}	Collector Cut-off Current	V_{CB}=230V, I_E=0			5.0	μA
I_{EBO}	Emitter Cut-off Current	V_{EB}=5V, I_C=0			5.0	μA
h_{FE1}	DC Current Gain	V_{CE}=5V, I_C=1A	55		160	
h_{FE2}	DC Current Gain	V_{CE}=5V, I_C=7A	35	60		
V_{CE}(sat)	Collector-Emitter Saturation Voltage	I_C=8A, I_B=0.8A		0.4	3.0	V
V_{BE}(on)	Base-Emitter On Voltage	V_{CE}=5V, I_C=7A		1.0	1.5	V
f_T	Current Gain Bandwidth Product	V_{CE}=5V, I_C=1A		30		MHz
C_{ob}	Output Capacitance	V_{CB}=10V, f=1MHz		200		pF

* Pulse Test: Pulse Width=20μs, Duty Cycle≤2%

Ordering Information

Part Number	Marking	Package	Packing Method	Remarks
2SC5200RTU	C5200R	TO-264	TUBE	hFE1 R grade
2SC5200OTU	C5200O	TO-264	TUBE	hFE1 O grade
FJL4315RTU	J4315R	TO-264	TUBE	hFE1 R grade
FJL4315OTU	J4315O	TO-264	TUBE	hFE1 O grade

Typical Characteristics

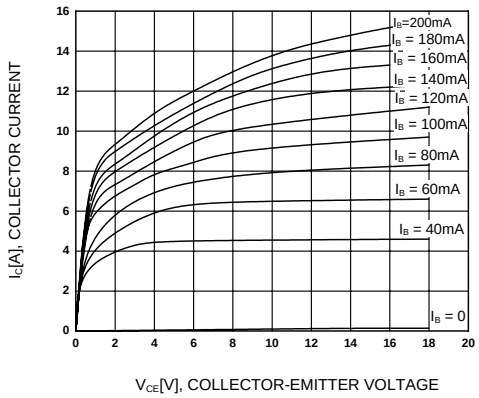


Figure 1. Static Characteristic

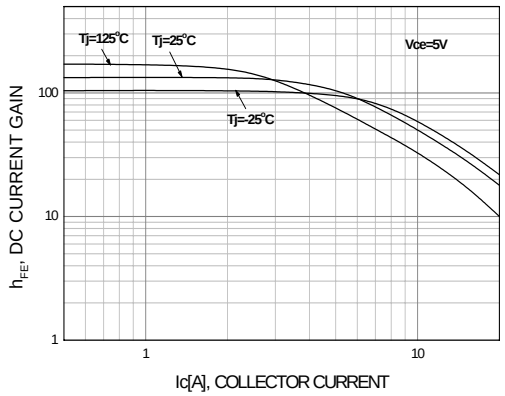


Figure 2. DC current Gain

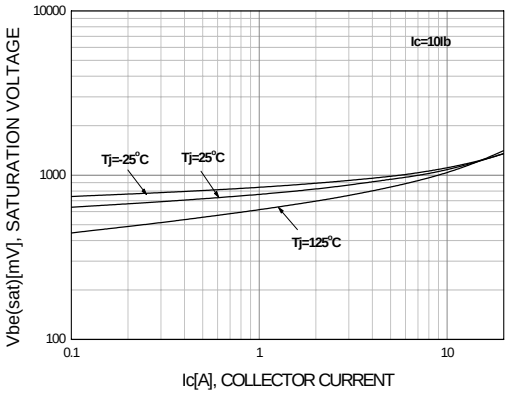


Figure 3. Base-Emitter Saturation Voltage

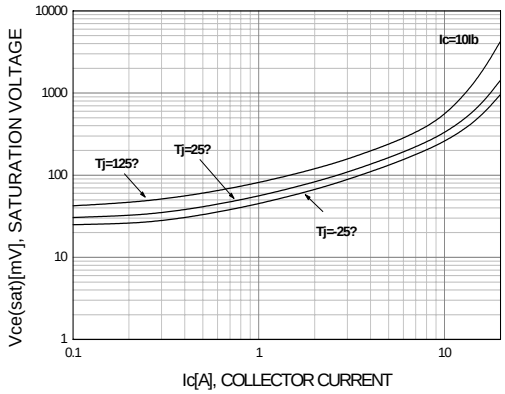


Figure 4. Collector-Emitter Saturation Voltage

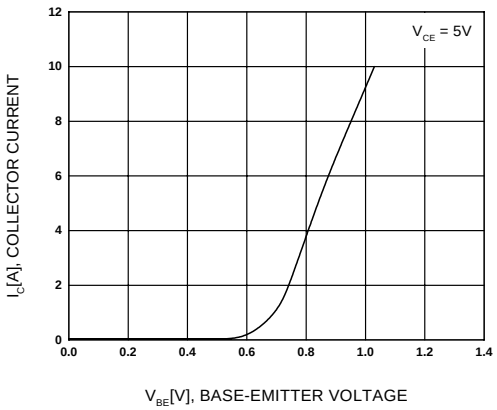


Figure 5. Base-Emitter On Voltage

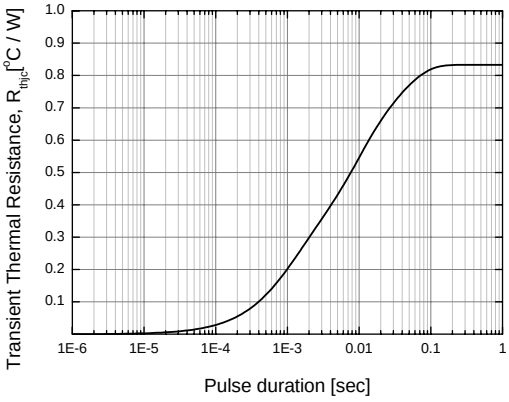


Figure 6. Thermal Resistance

Typical Characteristics

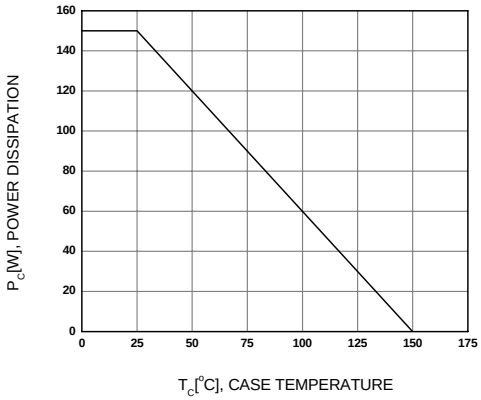


Figure 7. Power Derating

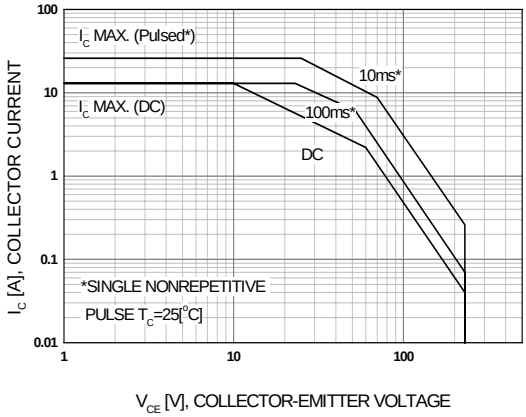
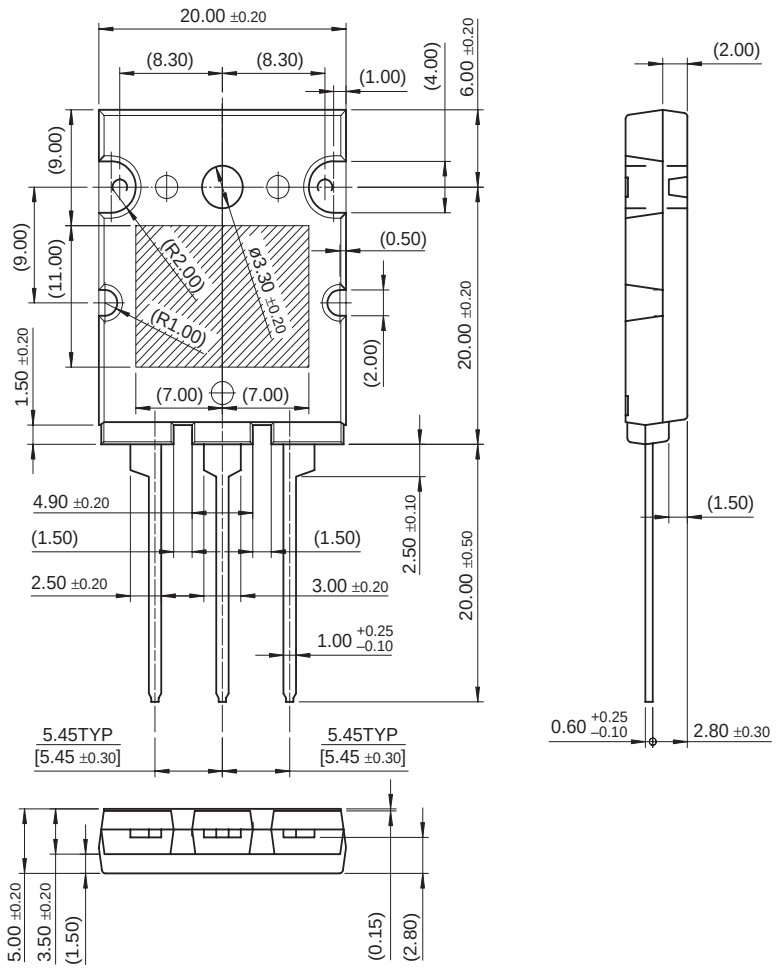


Figure 8. Safe Operating Area

Package Dimensions

TO-264



Dimensions in Millimeters

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FACT®	Motion-SPM™	SPM®	TinyWire™
FAST®	OPTOLOGIC®	STEALTH™	µSerDes™
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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
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Rev. I31

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http://moschip.ru/get-element

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На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

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